

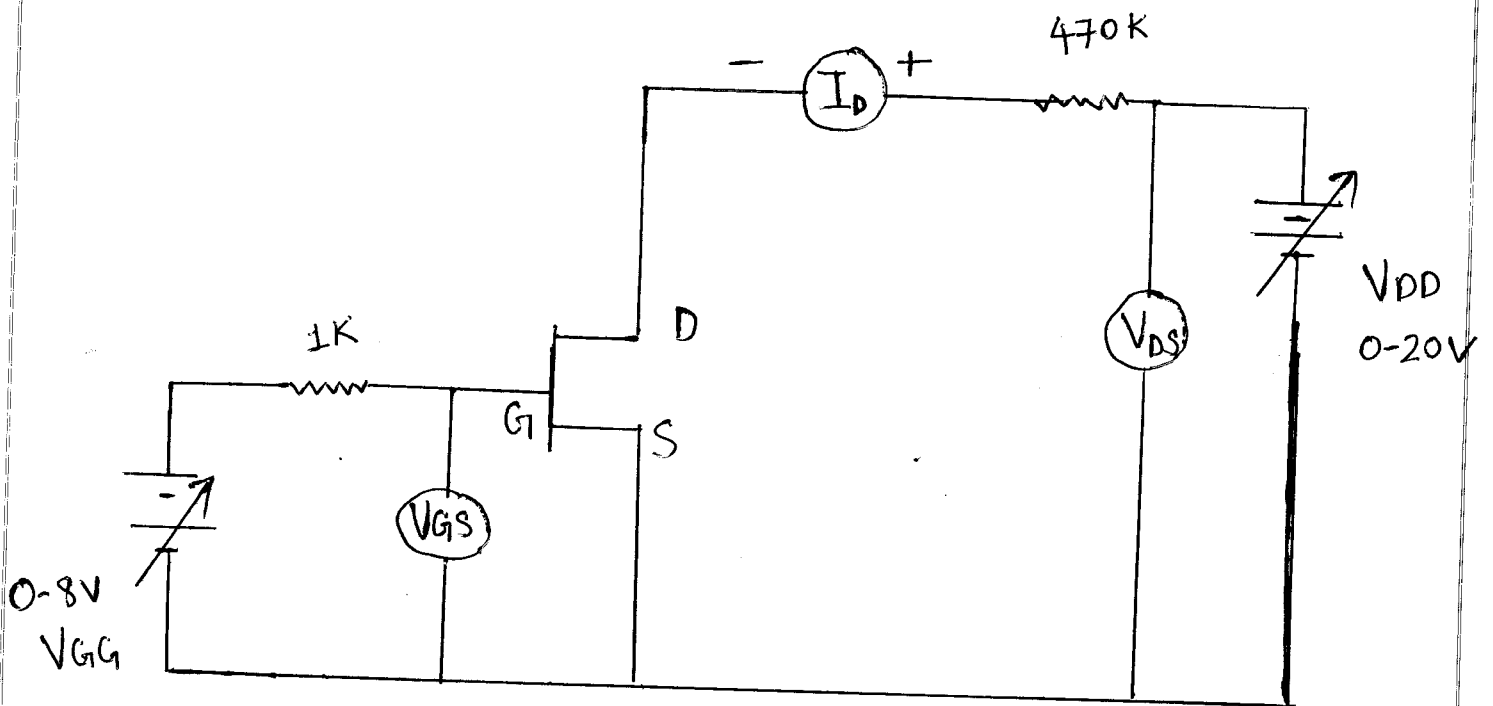
# CHARACTERISTICS OF MOSFET

# N-CHANNEL MOSFET OUTPUT AND TRANSFER CHARACTERISTICS

**Aim:** - To Study Transfer and Output Characteristics of an N- Channel MOSFET in common N Source Configuration.

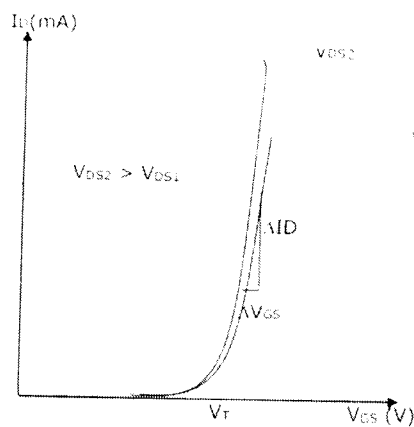
**Apparatus:** - MOSFET (IRF 540), Bread Board, Resistor ( $R_D$ ), Connecting Wires, Ammeter (mA), DC Power Supply (0-15 Volt), Voltmeter

**Circuit Diagram:** -

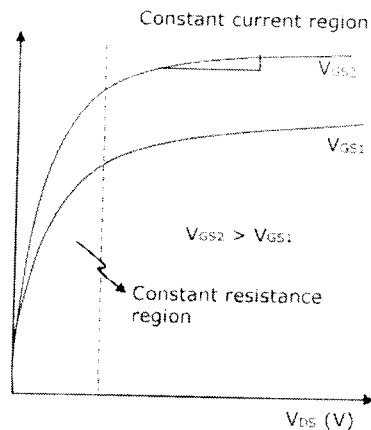


**Ideal Graph:**

**Transfer Characteristics:**



**Drain Characteristics**





## TRANSFER CHARACTERISTICS

VDS = 3 V	
VGS (V)	ID (mA)
0	
0.1	
0.2	
.	
.	
.	
.	
.	
.	
.	
3.5	

### CALCULATION:

1. **Threshold voltage  $V_T$**  : Gate to source voltage at which, drain current starts flowing.

2. **Transconductance  $g_m$**  : Ratio of small change in drain current ( $\Delta I_D$ ) to the corresponding change in gate to source voltage ( $\Delta V_{GS}$ ) for a constant  $V_{DS}$ .

$$g_m = \Delta I_D / \Delta V_{GS} \text{ at constant } V_{DS}$$

3. **Output drain resistance** : It is given by the relation of small change in drain to source voltage ( $\Delta V_{DS}$ ) to the corresponding change in Drain Current ( $\Delta I_D$ ) for a constant  $V_{GS}$ .

$$r_d \text{ or } r_o = \Delta V_{DS} / \Delta I_D \text{ at a constant } V_{GS}$$

### RESULTS:

1.  $V_T$  : \_\_\_\_\_

2.  $g_m$  : \_\_\_\_\_

3.  $r_o$  : \_\_\_\_\_

### CONCLUSION: